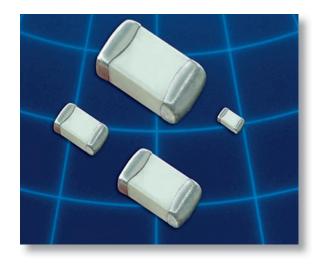
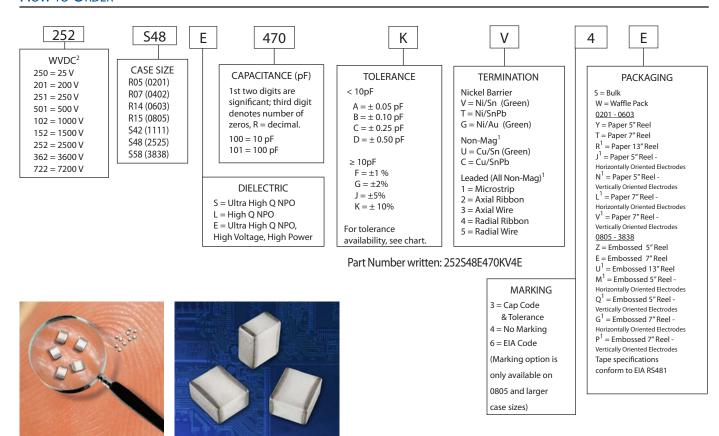
# Multi-Layer High-Q Capacitors



These lines of multilayer capacitors have been developed for High-Q and microwave applications.

- The S-Series (R07S, R14S, R15S) capacitors give an ultrahigh Q performance, and exhibit NP0 temperature characteristics.
- The L-Series (R05L) capacitors give mid-high Q performance, and exhibit NP0 temperature characteristics.
- The E-Series (S42E, S48E, S58E) capacitors give excellent high-Q performance from HF to Microwave frequencies. Typical uses are high voltage, high current applications. They are offered in chip (Ni barrier or Non-Magnetic Pt.-Ag) or in Non-Magnetic leaded form.
- RoHS compliance is standard for all unleaded parts (see termination options box).

### How to Order





<sup>&</sup>lt;sup>2</sup> - WVDC - Working Voltage DC.



# LOW ESR / HIGH-Q CAPACITOR SELECTION CHART

EIA Size						RF Power Applications								
				(R05)	0402	0603	0805	0805	11	11	2525	38	38	
Cap. Value		NPO (R05L)	NPO (R05G)	(R07S)	(R14S)	(R15S)	(R15G)	(S42E)		(S48E)	(S58E)			
Capac pF	citance Code													
0.1	OR1													
0.2	OR2		25/50 V	25 V	50/250 V	250 V			500V	1500V				
0.3	OR3		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V				
0.4	0R4		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V				
0.5	OR5		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V			
0.6	0R6		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
0.7	OR7		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
0.8	0R8		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
0.9	0R9		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
1.0	1R0		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
1.1	1R1	_	25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
1.2	1R2	Α	25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
1.3	1R3		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
1.4	1R4	В	25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
1.5	1R5		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
1.6	1R6	C	25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
1.7	1R7		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
1.8	1R8	<b>D</b>	25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
1.9	1R9	D	25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
2.0	2R0		25/50 V 25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
2.1	2R1 2R2		25/50 V	25 V 25 V	50/250 V 50/250 V	250 V 250 V	250 V 250 V	1000V 1000V	500V 500V	1500V 1500V	2500V 2500V	3600V 3600V	7200V 7200V	
2.2	2R2 2R4		25/50 V	25 V	50/250 V 50/250 V	250 V	250 V	1000V	500V	1500V	2500V 2500V	3600V	7200V 7200V	
2.7	2R7		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V 2500V	3600V	7200V	
3.0	3R0		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V 2500V	3600V	7200V	
3.3	3R3		25/50 V	25 V	50/250 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
3.6	3R6		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
3.9	3R9		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
4.3	4R3		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
4.7	4R7		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
5.1	5R1		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
5.6	5R6	A**	25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
6.2	6R2	В	25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
6.8	6R8		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
7.5	7R5	C	25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
8.2	8R2	D	25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
9.1	9R1		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
10	100		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
11	110		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
12	120	F	25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
13	130		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
15	150	_	25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
16	160	G	25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
18	180		25/50 V	25 V	50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
20	200	J	25/50 V		50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
22	220		25/50 V		50/200 V	250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V	
24 27	240 270	K	25/50 V 25/50 V		50/200 V	250 V	250 V 250 V	1000V	500V	1500V 1500V	2500V	3600V	7200V	
30	300		25/50 V 25/50 V		50/200 V 50 V	250 V 250 V	250 V 250 V	1000V 1000V	500V 500V	1500V	2500V 2500V	3600V 3600V	7200V 7200V	
33	330		25/50 V 25/50 V		50 V	250 V	250 V	1000V	500V	1500V	2500V 2500V	3600V	7200V 7200V	
رر	330		23/30 V		JU V	230 V	230 V	10001	J00 V	13000	23000	30007	/2001	

Consult factory for Non-Standard values.

<sup>\*\*</sup>A tolerance only available for R07S (0402) and R14S(0603) caps



# LOW ESR / HIGH-Q CAPACITOR SELECTION CHART

EIA Size						RF Power Applications							
				(R05)	0402	0603	0805	0805	1111		2525	38	38
Cap. Value		NPO (R05L)	NP0 (R05G)	(R07S)	(R14S)	(R15S)	(R15G)	(S42E)		(S48E)	(S58E)		
Capac pF	citance Code	Toler- ance											
36	360		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
39	390		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
43	430		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
47	470		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
51	510		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
56	560		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
62	620		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
68	680		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
75	750		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
82	820	F	25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
91	910		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
100	101		25/50 V			250 V	250 V	1000V	500V	1500V	2500V	3600V	7200V
110	111	G					250 V		300V	1500V	2500V	3600V	7200V
120	121						250 V		300V	1000V	2500V	3600V	7200V
130	131	† J					250 V		300V	1000V	2500V	3600V	7200V
150	151						250 V		300V	1000V	2500V	3600V	7200V
160	161	K					250 V		300V	1000V	2500V	3600V	7200V
180	181	- 1					250 V		300V	1000V	2500V	3600V	7200V
200	201						250 V		300V	1000V	2500V	3600V	72001
220	221						250 V		200V	1000V	2500V	3600V	
240	241						250 1		200V	600V	2500V	3600V	
270	271	-							200V	600V	2500V	3600V	
300	301	-							200V	600V	1500V	3600V	
330	331								200V	600V	1500V	3600V	
360	361								200V	600V	1500V	3600V	
390	391								200V	500V	1500V	3600V	
430	431								200V	500V	1500V	2500V	
470	471								200V	500V	1500V	2500V	
510	511								200V	500V	1000V	2500V	
560	561								200V	500V	1000V	2500V	
620	621								200V	500V	1000V	2500V	
680	681								200V	3000	1000V	2500V	
750	751								200V		1000V	2500V	
820	821								200V		1000V	2500V	
910	911	G							200V		1000V	1000V	
1000	102								200V		1000V	1000V	
1200	122	- J							2000		1000V	1000V	
1500	152										500V	1000V	
1800	182	K									500V	1000V	
2200	222	- ' \									300V	1000V	
2700	272										300V	500V	
3300	332									<del>                                     </del>	3000	500V	
3900	392											500V	
4700	472											500V	
5100	512											500V	
10000	103											3000	
10000	103				L			L					<u> </u>

Consult factory for Non-Standard values.

### DIELECTRIC CHARACTERISTICS

#### **NPO**

TEMPERATURE COEFFICIENT:  $0 \pm 30$ ppm /°C, -55 to 125°C

QUALITY FACTOR / DF: Q>1,000 @ 1KHz (C>1,000pF), Typical 10,000 (C<1,000 pF)

INSULATION RESISTANCE: >100 GΩ @ 25°C,WVDC¹;

125°C IR is 10% of 25°C rating

**DIELECTRIC STRENGTH:**  $500 \text{ V} \le 2.5 \text{ X WVDC}^{1} \text{ Min., } 25^{\circ}\text{C, } 50 \text{ mA max}$ 

> 1000 V ≤ 1.5 X WVDC¹ Min., 25°C, 50 mA max  $> 1500 = 1 \text{ X WVDC}^{1} \text{ Min., } 25^{\circ}\text{C, } 50 \text{ mA max}$

TEST PARAMETERS:: 1MHz ±50kHz, 1.0±0.2 VRMS, 25°C

AVAILABLE CAPACITANCE:

Size 1111: 0.2 - 1000 pF Size 0201: 0.2 - 100 pF Size 2525: 1.0 - 2700 pF 0.2 - 33 pF Size 0402: Size 3838: 1.0 - 5100 pF Size 0603: 0.2 - 100 pF

Size 0805: 0.3 - 220 pF

### MECHANICAL & ENVIRONMENTAL CHARACTERISTICS

**SPECIFICATION TEST PARAMETERS** 

SOLDERABILITY: Solder coverage ≥ 90% of metalized areas Preheat chip to 120°-150°C for 60 sec., dip terminals in rosin flux

No termination degradation then dip in Sn62 solder @ 240°±5°C for 5±1 sec **RESISTANCE TO** No mechanical damage Preheat device to 80°-100°C for 60 sec.

followed by 150°-180°C for 60 sec. Capacitance change: ±2.5% or 0.25pF SOLDERING HEAT:

Q>500 I.R. >10 G Ohms Dip in 260°±5°C solder for 10±1 sec. DWV2: 2.5 x WVDC1 Measure after 24±2 hour cooling period

**TERMINAL** Termination should not pull off. Linear pull force<sup>3</sup> exerted on axial leads soldered to each terminal. ADHESION: Ceramic should remain undamaged.

PCB DEFLECTION: No mechanical damage. Glass epoxy PCB: 0.5 mm deflection

Capacitance change: 2% or 0.5pF Max

LIFE TEST: MIL-STD-202, Method 108I Applied voltage: 200% of WVDC<sup>1</sup> for capacitors rated at 500 volts DC or less. No mechanical damage

100% of WVDC<sup>1</sup> for capacitors rated at 1250 volts DC or less.

Capacitance change: ±3.0% or 0.3 pF Temperature: 125°±3°C

Q>500 I.R. >1 G Ohms Test time: 1000+48-0 hours DWV2: 2.5 x WVDC1

5 cycles of: 30±3 minutes @ -55°+0/-3°C, THERMAL CYCLE: No mechanical damage. Capacitance change: ±2.5% or 0.25pF 2-3 min. @ 25°C, 30±3 min. @ +125°+3/-0°C,

Q>2000 I.R. >10 G Ohms 2-3 min. @ 25°C

DWV<sup>2</sup>: 2.5 x WVDC

Measure after 24±2 hour cooling period

No mechanical damage. Relative humidity: 90-95% STEADY STATE: Capacitance change: ±5.0% or 0.50pF max. Temperature: 40°±2°C

Q>300 I.R. ≥ 1 G-Ohm Test time: 500 +12/-0 Hours

DWV<sup>2</sup>: 2.5 x WVDC<sup>1</sup> Measure after 24±2 hour cooling period Applied voltage: 1.5 VDC, 50 mA max. No mechanical damage.

HUMIDITY. LOW VOLTAGE: Capacitance change: ±5.0% or 0.50pF max. Relative humidity: 85±2% Temperature: 40°±2°C

Q>300 I.R. = 1 G-Ohm min. Test time: 240 +12/-0 Hours DWV2: 2.5 x WVDC1 Measure after 24±2 hour cooling period

VIBRATION: No mechanical damage. Capacitance change: ±2.5% or 0.25pF Cycle performed for 2 hours in each of three perpendicular directions

O>1000 I.R. ≥ 10 G-Ohm Frequency range 10Hz to 55 Hz to 10 Hz traversed DWV2: 2.5 x WVDC1 in 1 minute. Harmonic motion amplitude: 1.5mm

<sup>&</sup>lt;sup>4</sup> - Whichever is less.



HUMIDITY,

<sup>&</sup>lt;sup>1</sup> - WVDC - Working Voltage DC.

<sup>&</sup>lt;sup>2</sup> - DWV - Dielectric Withstanding Voltage.

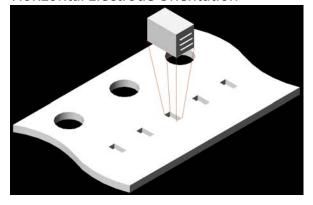
 $<sup>^{3}</sup>$  - 0402  $\geq$  2.0lbs, 0603  $\geq$  4.0lbs (min).

### MECHANICAL CHARACTERISTICS

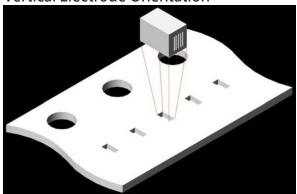
Size	Size Units		Width	Thickness	End Band	
EIA 0201	In	.024 ±.001	.012 ±.001	.012 ±.001	.008 Max.	
Metric (0603)	mm	(0.60 ±0.03)	(0.30 ±0.03)	(0.30 ±0.03)	(0.20 Max.)	
EIA 0402	In	.040 ±.004	.020 ±.004	.020 ±.004	.010 ±.006	
Metric (1005)	mm	(1.02 ±0.1)	(0.51 ±0.1)	(0.51 ±0.1)	(0.25 ±.15)	
EIA 0603	In	.062 ±.006	.032 ±.006	.030 +.005/003	.014 ±.006	
Metric (1608)	mm	(1.57 ±0.15)	(0.81 ±0.15)	(0.76 +.1308)	(0.35 ±.15)	
EIA 0805	In	.080 ±.008	.050 ±.008	.040 ±.006	.020 ±.010	
Metric (2012) mm		(2.03 ±0.20)	(1.27 ±0.20)	(1.02 ±.15)	(0.50 ±.25)	

### HORIZONTAL AND VERTICLE ORIENTED CAPACITORS

## Horizontal Electrode Orientation



## **Vertical Electrode Orientation**



## **APPLICATIONS & FEATURES**

Size: EIA 0201, 0402

Performance: SRF's up to 20 GHz, Ultra High Q, Tight tolerance, Ultralow ESR

Termination: Ni/Au, Ni/Sn, Ni/SnPb

Applications: High Frequency Wireless Communications, Portable Wireless Products, Battery Powered

**Products** 

**RoHS Compliant** 

### BENIFITS OF USING ORIENTED CAPACITORS

- Consistent Orientation Improved repeatability of production circuits.
- Consistent Orientation More consistent filter performance.
- Vertical Orientation The elimination of parallel frequencies.
- Vertical Orinetation Lower inductance for a given capacitor.
- Horizontal Orientation Lower coupling between adjacent capacitors.

## **E-S**ERIES TERMINATIONS AND LEADS

### CHIP DIMENSIONS

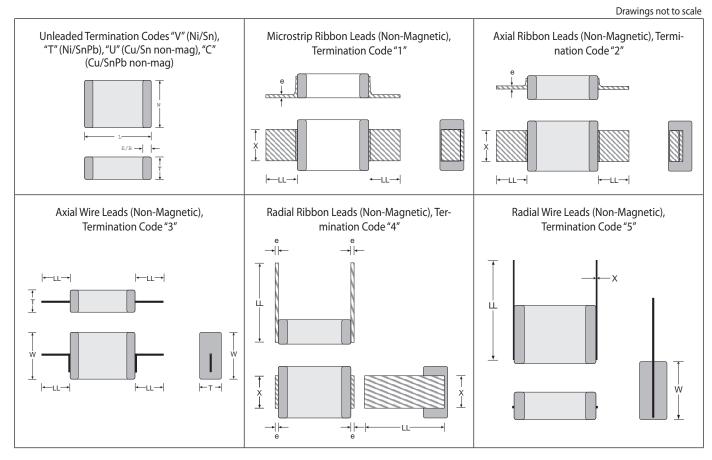
Termination	Size	Units	L	Tol	W	Tol	Т	E/B	Tol
	CADE	In	0.110	+.020010	0.110	+/015	0.102 Max.	0.015 Typ.	+/- 0.008
	S42E	mm	2.79	+0.51 -0.25	2.79	+/- 0.38	2.59 Max.	0.38 Typ.	+/- 0.20
V,T	S48E	In	0.230	+.025010	0.250	+/015	0.150 Max.	0.025 Typ.	
U,C	U.C 348E		5.84	+0.63 -0.25	6.35	+/- 0.38	3.81 Max.	0.63 Typ.	
","	СГОГ	In	0.380	+.015010	0.380	+/010	0.170 Max.	0.025 Typ.	
	S58E	mm	9.65	+0.38 -0.25	9.65	+/- 0.25	4.32 Max.	0.63 Typ.	

For all E-Series Models:

OPERATING TEMP.: -55 to +125°C INSULATION RESISTANCE: >10G  $\Omega$  @ 25°C TEMPERATURE COEFFICIENT: 0  $\pm$  30ppm /°C, -55 to 125°C

DISSIPATION FACTOR (TYP.): < 0.059

< 0.05% @ 1 MHz

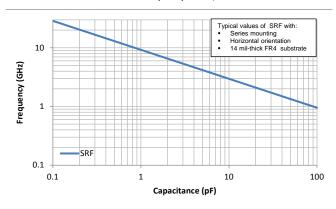


Lead	Size	LL(min)	Χ	Tol	е	e-Tol		
	C42F	0.25	0.093	0.093 +/-0.005		+/- 0.002		
	S42E	6.40	2.36	2.36 +/- 0.13 0.102		+/- 0.051		
1	CAOE	0.394	94 0.217 +/- 0.02 0.0		0.009	- 0.0019/+ 0.0031		
1	S48E	10.0	5.5	+/- 0.50	0.220	- 0.050/+ 0.080		
	CEOE	0.748	0.35	+/- 0.02	0.010	- 0.0019/+ 0.0039		
	S58E	19.00	8.90	+/- 0.50	0.250	- 0.050/+ 0.100		
	S42E	0.25	0.093	+/-0.005	0.004	+/- 0.002		
	34ZE	6.40	2.36	+/- 0.13	0.102	+/- 0.051		
2	S48E	0.394	0.217	+/- 0.02	0.009	- 0.0019/+ 0.0031		
2		10.00	5.50	+/- 0.50	0.220	- 0.050/+ 0.080		
	S58E	0.748	0.35	+/- 0.02	0.010	- 0.0019/+ 0.0039		
	330E	19.00	8.90	+/- 0.50	0.25	- 0.050/+ 0.100		
	S42E	0.25						
	34ZE	6.40	0.020in (0.511) diameter wire					
3	S48E	0.394						
)	340E	10.00		0.020111 (0	i i / Ulali	ictel wiic		
	S58E	0.748						
	SOCE	19.00						

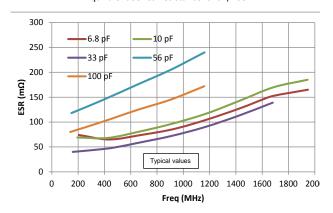
Lead	Size	LL(min)	Χ	Tol	е	e-Tol			
	C42F	0.352	0.093	+/-0.005	0.004	+/- 0.002			
	S42E	8.90	2.36	+/- 0.13	0.102	+/- 0.051			
	CAOE	0.501	0.217	+/- 0.02	0.009	- 0.0019/+ 0.0031			
4	S48E	12.70	5.50	+/- 0.50	0.220	- 0.050/+ 0.080			
	CEOE	0.886	0.35	+/- 0.02	0.010	- 0.0019/+ 0.0039			
	S58E	22.50	8.90	+/- 0.50	0.25	- 0.050/+ 0.100			
	S42E	0.25							
	34ZE	6.40	0.020in (0.511) diameter wire						
5	S48E	0.394							
Э		10.00							
	S58E	0.748							
	SOCE	19.00							

## RF CHARACTERISTICS - RO5L SERIES

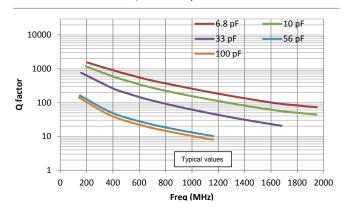
#### Resonant Frequency: 0201/R05L



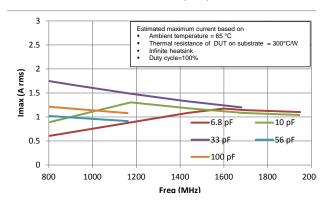
#### Equivalent Series Resistance: 0201/R05L



Q factor: 0201/R05L

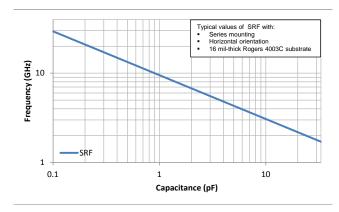


Maximum Current vs Frequency: 0201/R05L

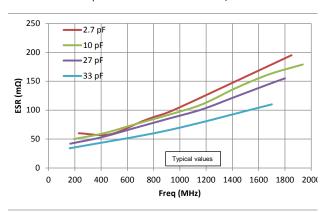


## RF CHARACTERISTICS - R07S-SERIES

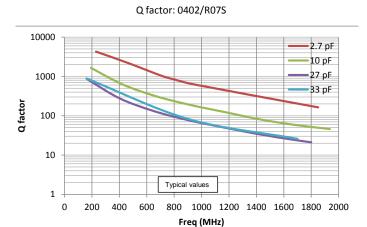
Resonant Frequency: 0402/R07S



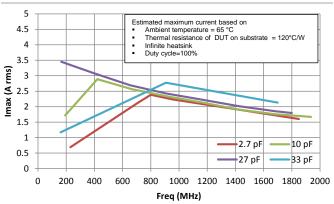
Equivalent Series Resistance: 0402/R07S



### RF CHARACTERISTICS R07S SERIES

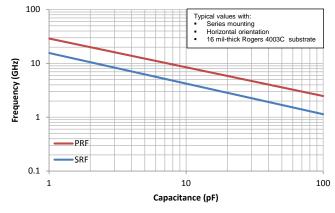


#### Maximum Current vs Frequency: 0402/R07S

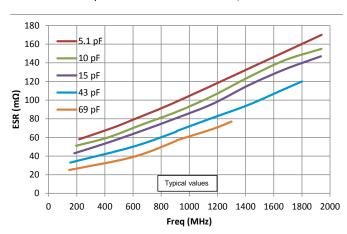


## RF CHARACTERISTICS R14S SERIES

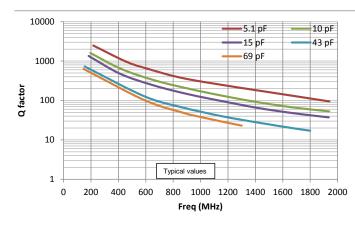




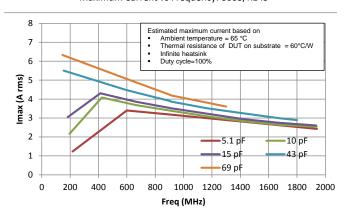
#### Equivalent Series Resistance: 0603/R14S



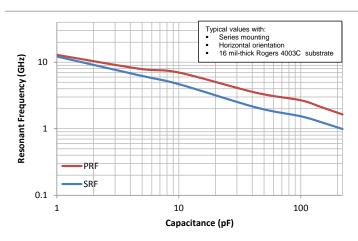
Q factor: 0603/R14S



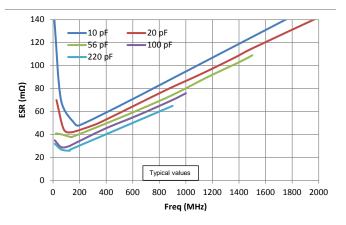
Maximum Current vs Frequency: 0603/R14S



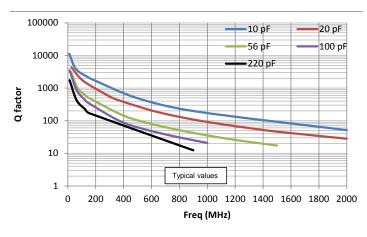
Resonant Frequency: 0805/R15S



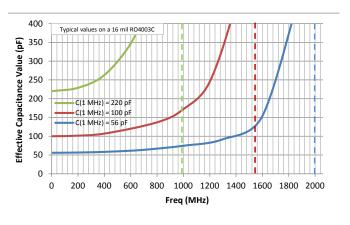
Equivalent Series Resistance: 0805/R15S



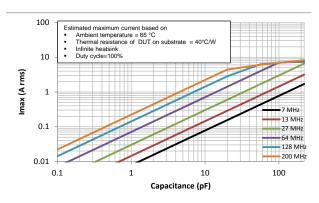
Q factor: 0805/R15S



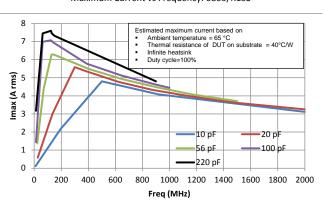
Effective capacitance value: 0805/R15S



Maximum Current vs Capacitance: 0805/R15S

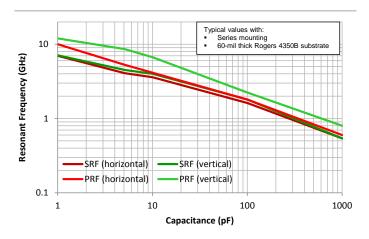


Maximum Current vs Frequency: 0805/R15S

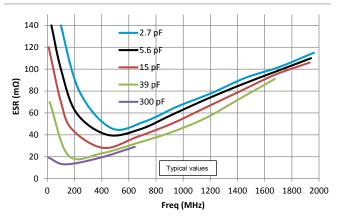


## RF CHARACTERISTICS - S24E SERIES

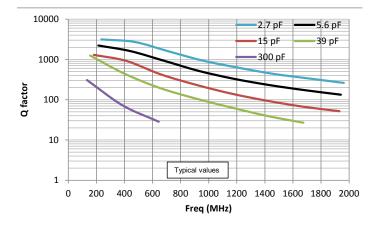
Resonant frequencies: 1111/S42E



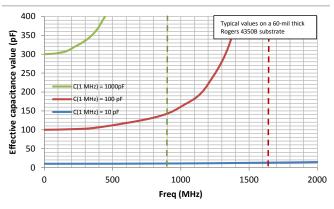
Equivalent Series Resistance: 1111/S42E



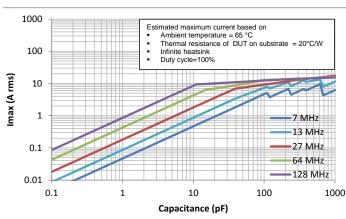
Q factor: 1111/S42E



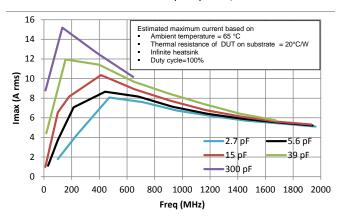
Effective capacitance value: 1111/S42E



Maximum Current vs Capacitance 1111/S42E

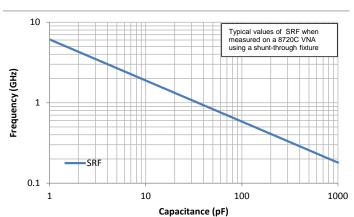


Maximum Current vs Frequency: 1111/S42E

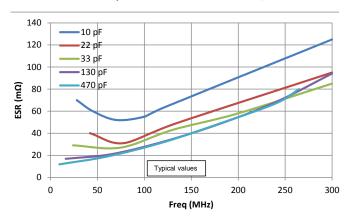


## RF CHARACTERISTICS - S48E SERIES

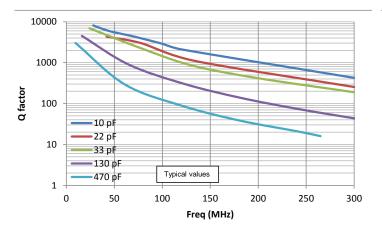




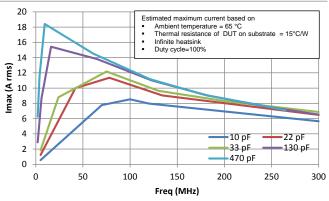
#### Equivalent Series Resistance: 2525/S48E



Q factor: 2525/S48E

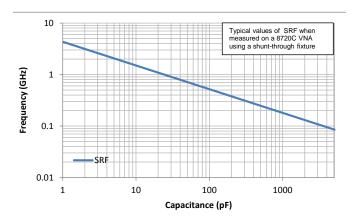


Maximum Current vs Frequency: 2525/S48E

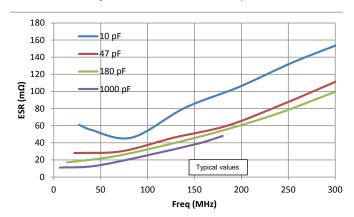


## RF CHARACTERISTICS - S58E SERIES

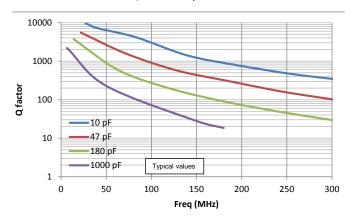
### Resonant Frequency: 3838/S58E



#### Equivalent Series Resistance: 3838/S58E



Q factor: 3838/S58E



Maximum Current vs Frequency: 3838/S58E

